



M T B F

(E I A J R C R - 9 1 0 2)

Model	TUXS200F42
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	17	0.5650	
2		Hybrid	0	0.0000	
3	Transistors		14	0.7986	
4	Diodes		33	0.5580	
5	LED•Optocouplers		2	0.1400	
6	Resistors		130	0.6702	
7	Capacitors		90	0.6660	
8	Transformer•Choke Coil		4	0.0920	
9	Connectors		766	0.2374	
10	Others		2	0.1130	
Total Failure Rate [10 ⁻⁶ /H]				3.8402	

M T B F	[H]	260,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—